

SN74LVC1G3157 Single-Pole Double-Throw Analog Switch

1 Features

- ESD Protection Exceeds JESD 22
 - 2000-V Human Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)
- 1.65-V to 5.5-V V_{CC} Operation
- Qualified For 125°C operation
- Specified Break-Before-Make Switching
- Rail-to-Rail Signal Handling
- Operating Frequency Typically 340 MHz at Room Temperature
- High Speed, Typically 0.5 ns ($V_{CC} = 3\text{ V}$, $C_L = 50\text{ pF}$)
- Low ON-State Resistance, Typically $\pm 6\ \Omega$ ($V_{CC} = 4.5\text{ V}$)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

2 Applications

- Wearables and Mobile Devices
- Portable Computing
- Internet of Things (IoT)
- Audio Signal Routing
- Remote Radio Unit
- Portable Medical Equipment
- Surveillance
- Home Automation
- I2C/SPI/UART Bus Multiplexing
- Wireless Charging

3 Description

This single channel single-pole double-throw (SPDT) analog switch is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G3157 device can handle both analog and digital signals. The SN74LVC1G3157 device permits signals with amplitudes of up to V_{CC} (peak) to be transmitted in either direction.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC1G3157	SOT-23 (DBV)	2.90 mm × 1.60 mm
	SC70 (DCK)	2.00 mm × 1.25 mm
	SOT (DRL)	1.60 mm × 1.20 mm
	SON (DRY)	1.45 mm × 1.00 mm
	DSBGA (YZP)	1.41 mm × 0.91 mm
	SON (DSF)	1.00 mm × 1.00 mm
	X2SON (DTB)	0.80 mm × 1.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

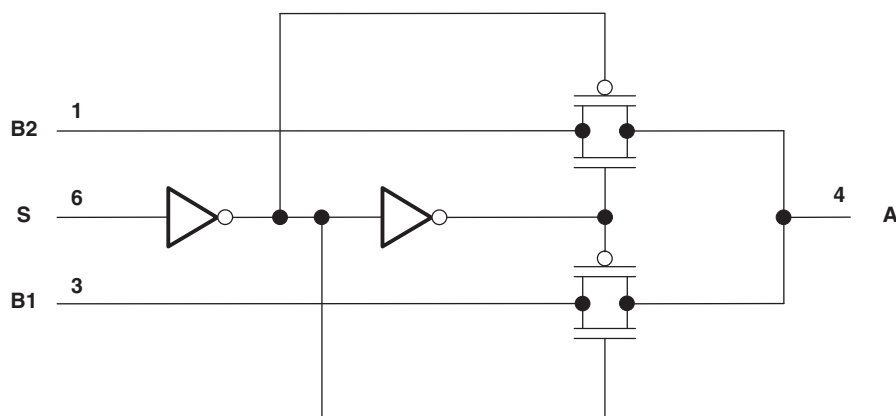


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision K (January 2017) to Revision L	Page
Deleted <i>Feature</i> "Useful for Both Analog and Digital Applications"	1
Deleted <i>Feature</i> "High Degree of Linearity"	1
Changed the first sentence of the <i>Description</i> From: "This single-pole double-throw (SPDT)..." To: "This single channel single pole double-throw (SPDT)..."	1
Added the X2SON (DTB) package to the <i>Device Information</i>	1
Added the X2SON (DTB) package to the <i>Pin Configuration and Functions</i>	4
Changed $I_{I/O}$ To: $I_{I/OK}$ for I/O port diode current in the <i>Absolute Maximum Ratings</i>	5
Added the DTB (X2SON) package to the <i>Thermal Information</i> table	6
Changed Note 1 and Note 2 in the <i>Analog Switch Characteristics</i> table	9
Deleted Note 3 "Specified by design" from the <i>Analog Switch Characteristics</i> tables	9
Deleted Note 4 "Specified by design" from the <i>Switch Characteristics 85°C</i> tables	9
Deleted Note 4 "Specified by design" from the <i>Switch Characteristics 125°C</i> tables	9
Changed Figure 3 , From: $SW1 = V_{IL}$ to $SW1 = V_{IH}$, From: $SW2 = V_{IH}$ to: $SW2 = V_{IL}$	10
Changed Figure 6	12
Added a series 50- Ω resistor on B1 in Figure 7	12
Changed Figure 8	13

Changes from Revision J (June 2016) to Revision K	Page
Added new applications to <i>Applications</i> section	1
Added Operating free-air temperature, T_A for BGA and all other packages in <i>Recommended Operating Conditions</i>	6
Added 125°C data to <i>Electrical Characteristics</i> table.	7
Added 85°C to title to differentiate from new 125°C <i>Switching Characteristics</i> section.	9
Added 125°C <i>Switching Characteristics</i> section and data.	9

Changes from Revision I (June 2015) to Revision J
Page

Deleted 200-V Machine Model (A115-A) from <i>Features</i>	1
Changed <i>Feature</i> From: "Operating Frequency Typically 300 MHz at Room Temperature" To: "Operating Frequency Typically 340 MHz at Room Temperature"	1
Updated <i>Device Information</i> table	1
Updated pinout images for all packages	4
Added temperature ranges for Storage temperature, T_{stg} and Junction temperature, T_J in <i>Absolute Maximum Ratings</i>	5
Changed MAX value ± 1 to ± 0.1 for I_{off} and I_{IN} in <i>Electrical Characteristics</i> table.....	7
Added <i>Receiving Notification of Documentation Updates</i> section	19

Changes from Revision H (May 2012) to Revision I
Page

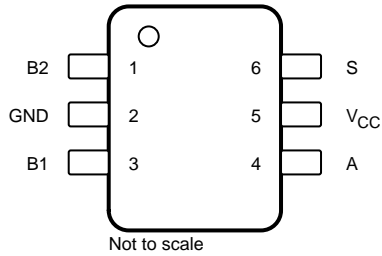
Added <i>Device Information</i> table, <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes, Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1
Updated <i>Features</i>	1

Changes from Revision G (September 2011) to Revision H
Page

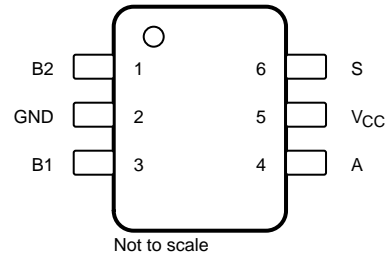
Changed YZP with correct pin labels.	4
Added <i>Thermal Information</i> table	6
Changed to correct Pin Label "S"	7

5 Pin Configuration and Functions

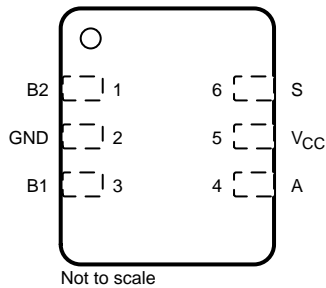
DBV Package
6-Pin SOT-23
Top View



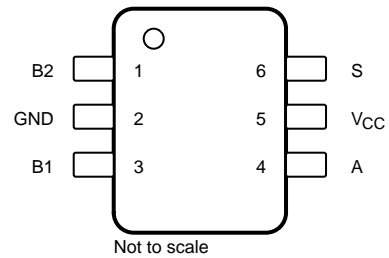
DCK Package
6-Pin SC70
Top View



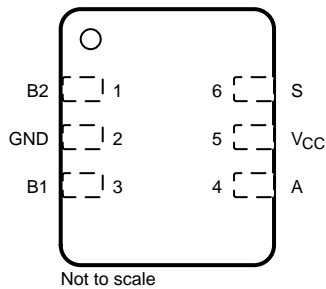
DRY Package
6-Pin SON
Top View



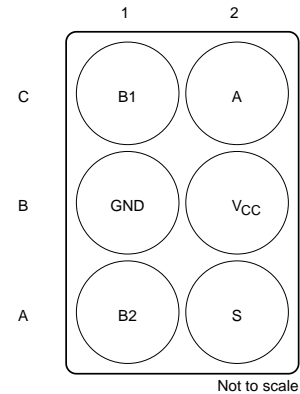
DRL Package
6-Pin SOT
Top View



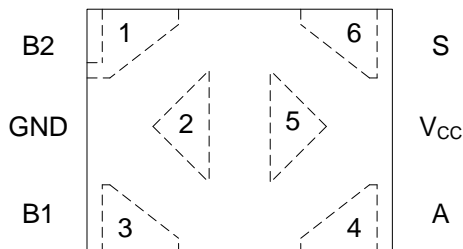
DSF Package
6-Pin SON
Top View



YZP Package
6-Pin DSBGA
Bottom View



DTB Package
6-Pin X2SON
Top View



Pin Functions

NAME	PIN		I/O	DESCRIPTION
	SOT-23, SC70, SON, X2SON, or SOT	DSBGA		
B2	1	A1	I/O	Switch I/O. Set S high to enable.
GND	2	B1	—	Ground
B1	3	C1	I/O	Switch I/O. Set S low to enable.
A	4	C2	I/O	Common terminal
V _{CC}	5	B2	—	Power supply
S	6	A2	I	Select

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾		−0.5	6.5	V
V _{IN}	Control input voltage ^{(2) (3)}		−0.5	6.5	V
V _{I/O}	Switch I/O voltage ^{(2) (3) (4) (5)}		−0.5	V _{CC} + 0.5	V
I _{IK}	Control input clamp current	V _{IN} < 0	−50		mA
I _{I/OK}	I/O port diode current	V _{I/O} < 0 or V _{I/O} > V _{CC}	±50		mA
I _{I/O}	On-state switch current ⁽⁶⁾	V _{I/O} = 0 to V _{CC}	±128		mA
	Continuous current through V _{CC} or GND		±100		mA
T _J	Junction temperature		150		°C
T _{stg}	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground unless otherwise specified.
- (3) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) This value is limited to 5.5 V maximum.
- (5) V_I, V_O, V_A, and V_{BN} are used to denote specific conditions for V_{I/O}.
- (6) I_I, I_O, I_A, and I_{BN} are used to denote specific conditions for I_{I/O}.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

SN74LVC1G3157

SCES424L – JANUARY 2003 – REVISED MAY 2017

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		1.65	5.5	V
V _{I/O}	Switch input or output voltage		0	V _{CC}	V
V _{IN}	Control input voltage		0	5.5	V
V _{IH}	High-level input voltage, control input	V _{CC} = 1.65 V to 1.95 V	V _{CC} × 0.75	V	
		V _{CC} = 2.3 V to 5.5 V	V _{CC} × 0.7		
V _{IL}	Low-level input voltage, control input	V _{CC} = 1.65 V to 1.95 V	V _{CC} × 0.25	V	
		V _{CC} = 2.3 V to 5.5 V	V _{CC} × 0.3		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 1.65 V to 1.95 V	20	ns/V	
		V _{CC} = 2.3 V to 2.7 V	20		
		V _{CC} = 3 V to 3.6 V	10		
		V _{CC} = 4.5 V to 5.5 V	10		
T _A	Operating free-air temperature	BGA package (YZP)	−40	85	°C
		All other packages (DBV, DCK, DRL, DRY, DSF)	−40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, [Implications of Slow or Floating CMOS Inputs](#) (SCBA004).

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74LVC1G3157						UNIT
		DBV (SOT-23)	DCK (SC70)	DRL (SOT)	DRY (SON)	DTB (X2SON)	YZP (DSBGA)	
		6 PINS	6 PINS	6 PINS	6 PINS	6 PINS	6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	234.9	269.5	244.1	284.2	324.5	129.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	150.4	189.5	112.5	138.6	150.5	1.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	86.4	84.7	109.9	170.9	239.0	40.0	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	60.8	62.7	9.3	13.7	17.2	0.6	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	86.1	84.0	109.3	167.9	238.3	40.2	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS			V _{CC}	T _A = -40 to 85°C			T _A = -40 to 125°C			UNIT
							MIN	TYP ⁽¹⁾	MAX	MIN	TYP ⁽¹⁾	MAX	
r _{on}	ON-state switch resistance ⁽²⁾		See Figure 1 and Figure 2	V _I = 0 V	I _O = 4 mA	1.65 V		11	20		11	20	Ω
				V _I = 1.65 V	I _O = -4 mA			15	50		15	50	
				V _I = 0 V	I _O = 8 mA	2.3 V		8	12		8	12	
				V _I = 2.3 V	I _O = -8 mA			11	30		11	30	
				V _I = 0 V	I _O = 24 mA	3 V		7	9		7	9	
				V _I = 3 V	I _O = -24 mA			9	20		9	20	
				V _I = 0 V	I _O = 30 mA	4.5 V		6	7		6	7	
				V _I = 2.4 V	I _O = -30 mA			7	12		7	12	
				V _I = 4.5 V	I _O = -30 mA			7	15		7	15	
r _{range}	ON-state switch resistance over signal range ⁽²⁾⁽³⁾		0 ≤ V _{Bn} ≤ V _{CC} (see Figure 1 and Figure 2)	I _A = -4 mA	1.65 V			140			140	Ω	
				I _A = -8 mA	2.3 V			45			45		
				I _A = -24 mA	3 V			18			18		
				I _A = -30 mA	4.5 V			10			10		
Δr _{on}	Difference of ON-state resistance between switches ⁽²⁾⁽⁴⁾⁽⁵⁾		See Figure 2	V _{Bn} = 1.15 V	I _A = -4 mA	1.65 V		0.5			0.5	Ω	
				V _{Bn} = 1.6 V	I _A = -8 mA	2.3 V		0.1			0.3		
				V _{Bn} = 2.1 V	I _A = -24 mA	3 V		0.1			0.3		
				V _{Bn} = 3.15 V	I _A = -30 mA	4.5 V		0.1			0.2		
r _{on(flat)}	ON resistance flatness ⁽²⁾⁽⁴⁾⁽⁶⁾		0 ≤ V _{Bn} ≤ V _{CC}	I _A = -4 mA	1.65 V			110			110	Ω	
				I _A = -8 mA	2.3 V			26			40		
				I _A = -24 mA	3 V			9			10		
				I _A = -30 mA	4.5 V			4			5		
I _{off} ⁽⁷⁾	OFF-state switch leakage current		0 ≤ V _I , V _O ≤ V _{CC} (see Figure 3)			1.65 V to 5.5 V			±1			±1	μA
								±0.05	±0.1 ⁽¹⁾		±0.05	±0.1	
I _{S(on)}	ON-state switch leakage current		V _I = V _{CC} or GND, V _O = Open (see Figure 4)			5.5 V			±1			±1	μA
								±0.1 ⁽¹⁾			±0.1 ⁽¹⁾		
I _{IN}	Control input current		0 ≤ V _{IN} ≤ V _{CC}			0 V to 5.5 V			±1			±1	μA
								±0.05	±0.1 ⁽¹⁾		±0.05	±0.1	
I _{CC}	Supply current		S = V _{CC} or GND			5.5 V		1	10			35	μA
ΔI _{CC}	Supply-current change		S = V _{CC} - 0.6 V			5.5 V			500			500	μA
C _i	Control input capacitance	S				5 V		2.7			2.7		pF
C _{io(off)}	Switch input/output capacitance	Bn				5 V		5.2			5.2		pF
C _{io(on)}	Switch input/output capacitance	Bn				5 V		17.3			17.3		pF
		A						17.3			17.3		

(1) T_A = 25°C

(2) Measured by the voltage drop between I/O pins at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages on the two (A or B) ports.

(3) Specified by design

(4) Δr_{on} = r_{on(max)} - r_{on(min)} measured at identical V_{CC}, temperature, and voltage levels

(5) This parameter is characterized, but not production tested.

(6) Flatness is defined as the difference between the maximum and minimum values of on-state resistance over the specified range of conditions.

(7) I_{off} is the same as I_{S(off)} (off-state switch leakage current).

6.6 Analog Switch Characteristics

 $T_A = 25^\circ\text{C}$

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CC}	TYP	UNIT
Frequency response ⁽¹⁾ (switch on)	A or Bn	Bn or A	$R_L = 50\ \Omega$, $f_{in} =$ sine wave (see Figure 6)	1.65 V	340	MHz
				2.3 V	340	
				3 V	340	
				4.5 V	340	
Crosstalk ⁽²⁾ (between switches)	B1 or B2	B2 or B1	$R_L = 50\ \Omega$, $f_{in} = 10\ \text{MHz}$ (sine wave) (see Figure 7)	1.65 V	–54	dB
				2.3 V	–54	
				3 V	–54	
				4.5 V	–54	
Feed through attenuation ⁽²⁾ (switch off)	A or Bn	Bn or A	$C_L = 5\ \text{pF}$, $R_L = 50\ \Omega$, $f_{in} = 10\ \text{MHz}$ (sine wave) (see Figure 8)	1.65 V	–57	dB
				2.3 V	–57	
				3 V	–57	
				4.5 V	–57	
Charge injection	S	A	$C_L = 0.1\ \text{nF}$, $R_L = 1\ \text{M}\Omega$ (see Figure 9)	3.3 V	3	pC
				5 V	7	
Total harmonic distortion	A or Bn	Bn or A	$V_I = 0.5\ \text{V}_{p-p}$, $R_L = 600\ \Omega$, $f_{in} = 600\ \text{Hz}$ to $20\ \text{kHz}$ (sine wave) (see Figure 10)	1.65 V	0.1%	
				2.3 V	0.025%	
				3 V	0.015%	
				4.5 V	0.01%	

(1) Set f_{in} to 0 dBm and provide a bias of 0.4 V. Increase f_{in} frequency until the gain is 3 dB below the insertion loss.

(2) Set f_{in} to 0 dBm and provide a bias of 0.4 V.

6.7 Switching Characteristics 85°C

$T_A = -40$ to $+85^\circ\text{C}$ (see Figure 5 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{pd}^{(1)}$	A or Bn	Bn or A		2		1.2		0.8		0.3	ns
$t_{en}^{(2)}$	S	Bn	7	24	3.5	14	2.5	7.6	1.7	5.7	ns
$t_{dis}^{(3)}$			3	13	2	7.5	1.5	5.3	0.8	3.8	
t_{B-M}			0.5		0.5		0.5		0.5		ns

- (1) t_{pd} is the slower of t_{PLH} or t_{PHL} . The propagation delay is calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
- (2) t_{en} is the slower of t_{PZL} or t_{PZH} .
- (3) t_{dis} is the slower of t_{PLZ} or t_{PHZ} .

6.8 Switching Characteristics 125°C

$T_A = -40$ to $+125^\circ\text{C}$ (see Figure 5 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{pd}^{(1)}$	A or Bn	Bn or A		2		1.2		0.8		0.5	ns
$t_{en}^{(2)}$	S	Bn	1	24.5	1	14.5	2.5	8	1.7	6	ns
$t_{dis}^{(3)}$			2.5	13.5	2	8	1.5	5.5	0.8	4	
t_{B-M}			0.5		0.5		0.5		0.5		ns

- (1) t_{pd} is the slower of t_{PLH} or t_{PHL} . The propagation delay is calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
- (2) t_{en} is the slower of t_{PZL} or t_{PZH} .
- (3) t_{dis} is the slower of t_{PLZ} or t_{PHZ} .

6.9 Typical Characteristics

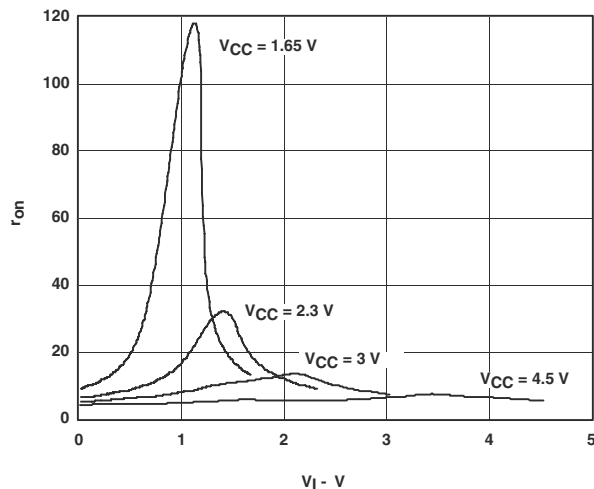


Figure 1. Typical r_{on} as a Function of Input Voltage (V_I) for $V_I = 0$ to V_{CC}

7 Parameter Measurement Information

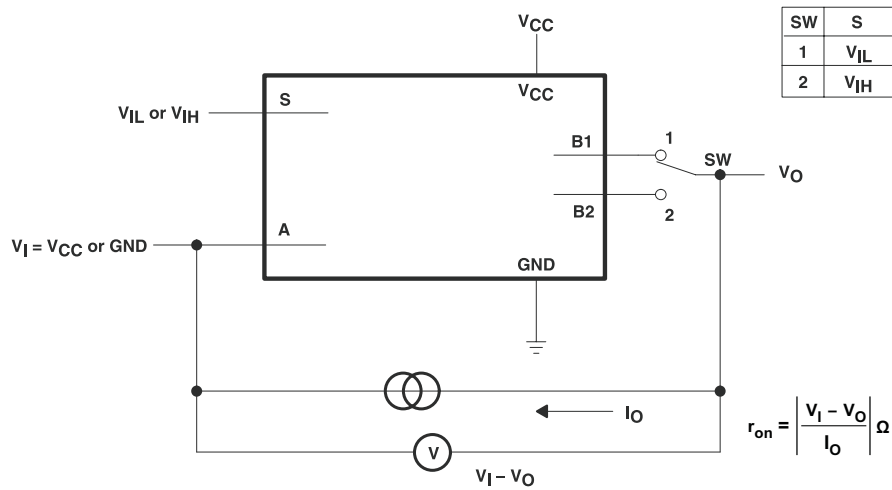


Figure 2. ON-State Resistance Test Circuit

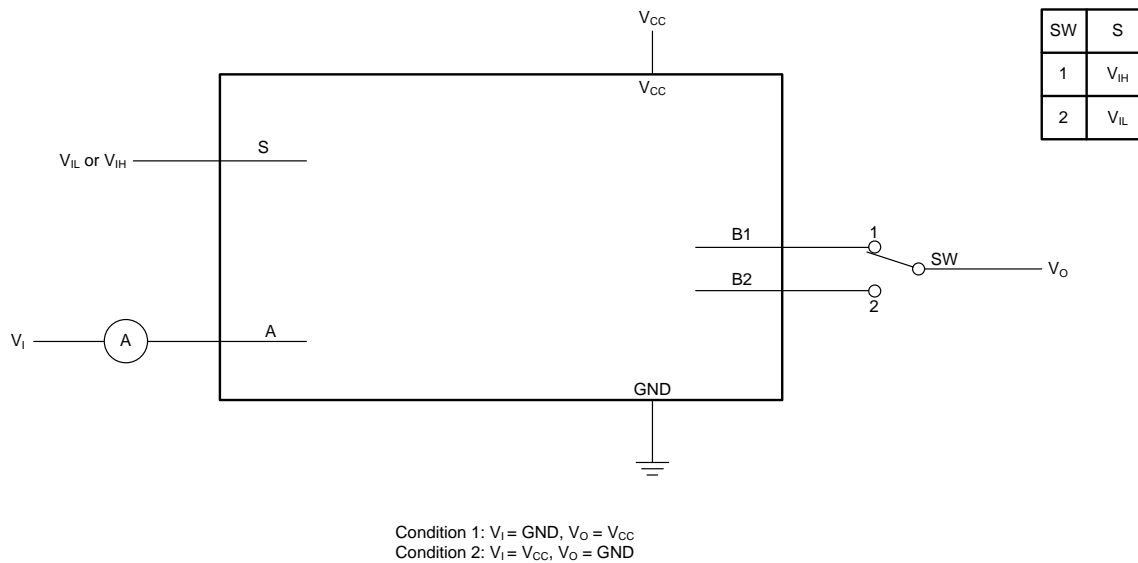


Figure 3. OFF-State Switch Leakage-Current Test Circuit

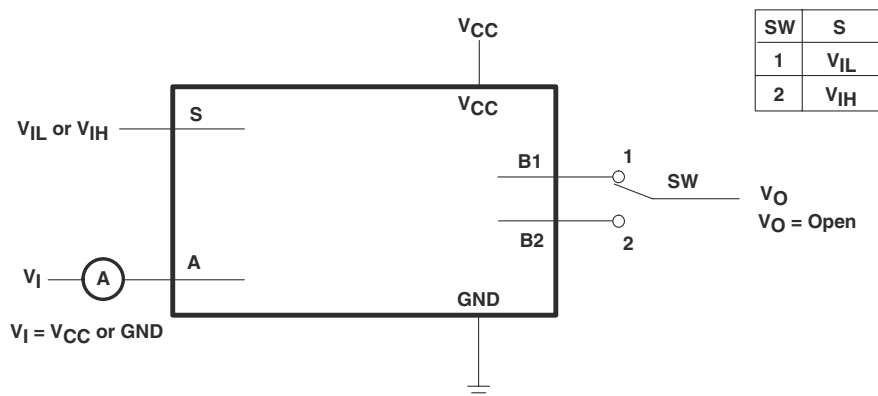
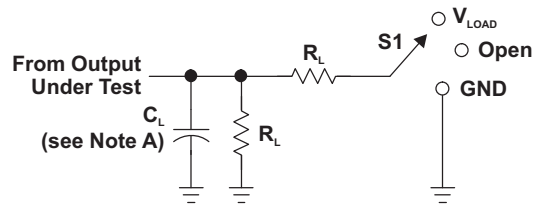


Figure 4. ON-State Switch Leakage-Current Test Circuit

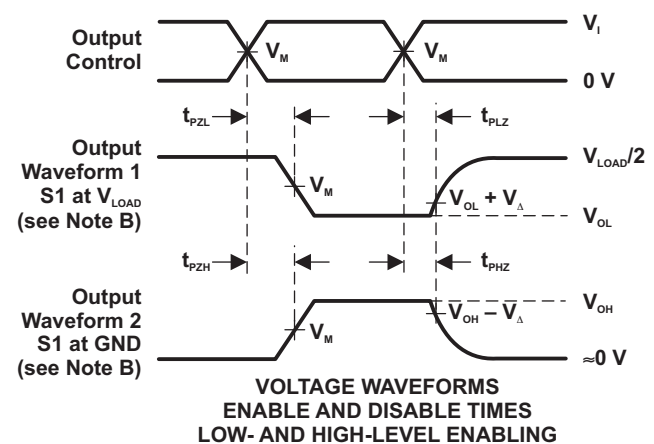
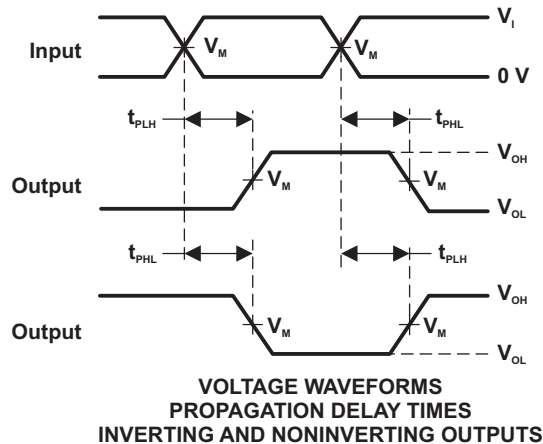
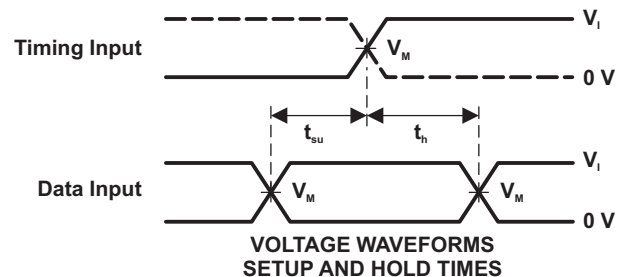
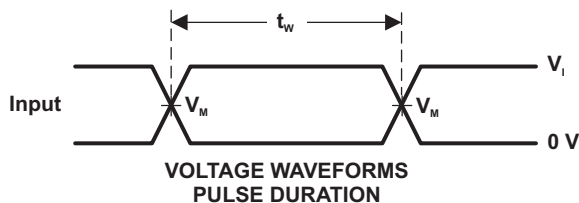
Parameter Measurement Information (continued)



LOAD CIRCUIT

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_A
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V
$3.3\text{ V} \pm 0.3\text{ V}$	V_{CC}	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V
$5\text{ V} \pm 0.5\text{ V}$	V_{CC}	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_o = 50\text{ }\Omega$.
 - The outputs are measured one at a time, with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{on} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .
 - All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms

Parameter Measurement Information (continued)

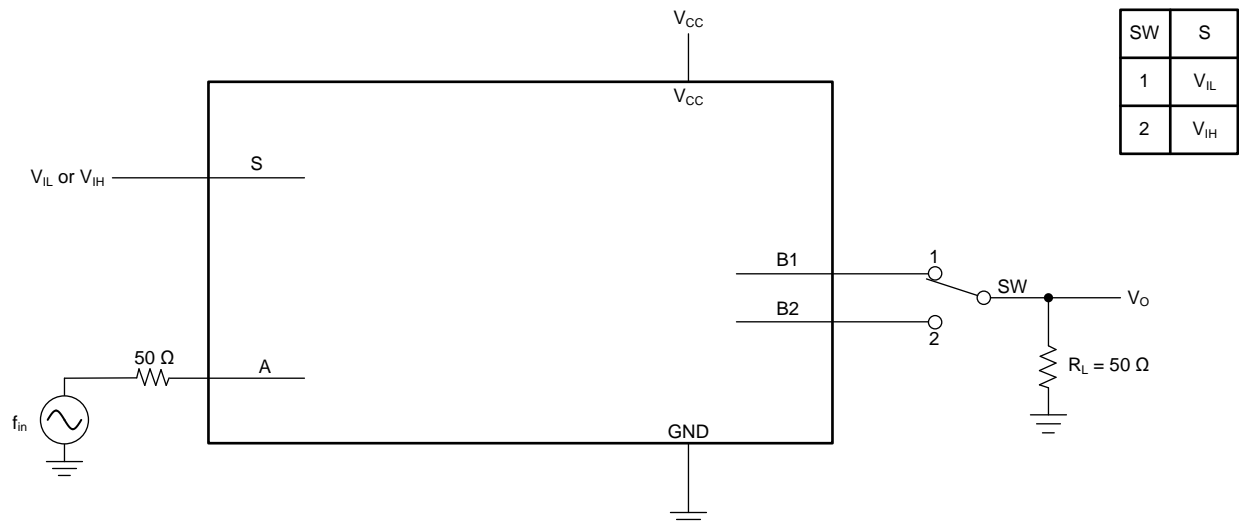


Figure 6. Frequency Response (Switch On)

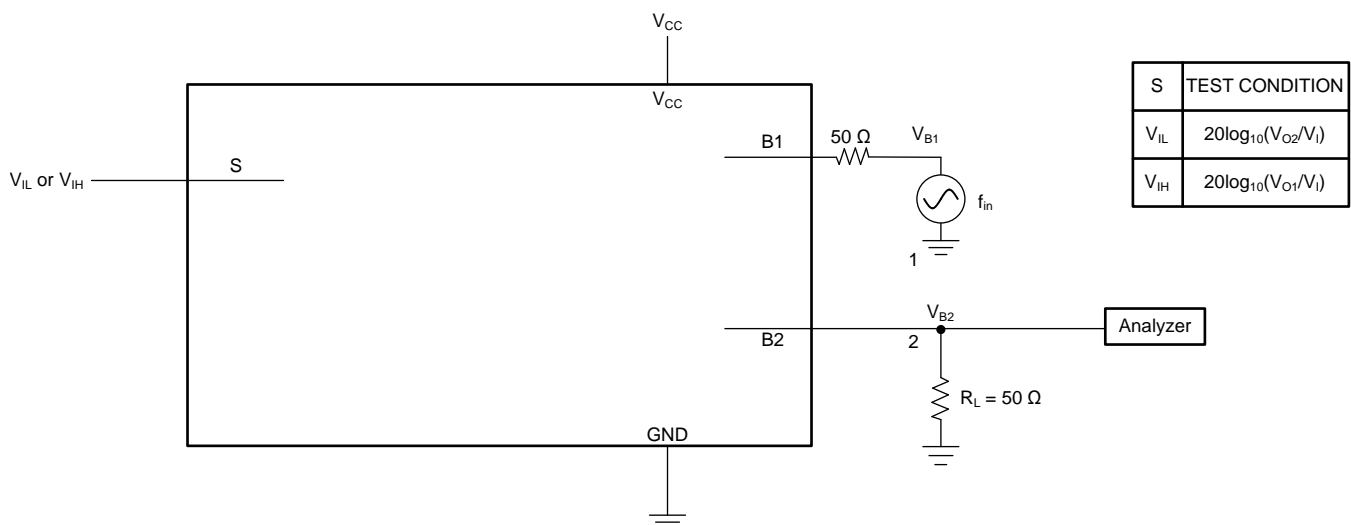


Figure 7. Crosstalk (Between Switches)

Parameter Measurement Information (continued)

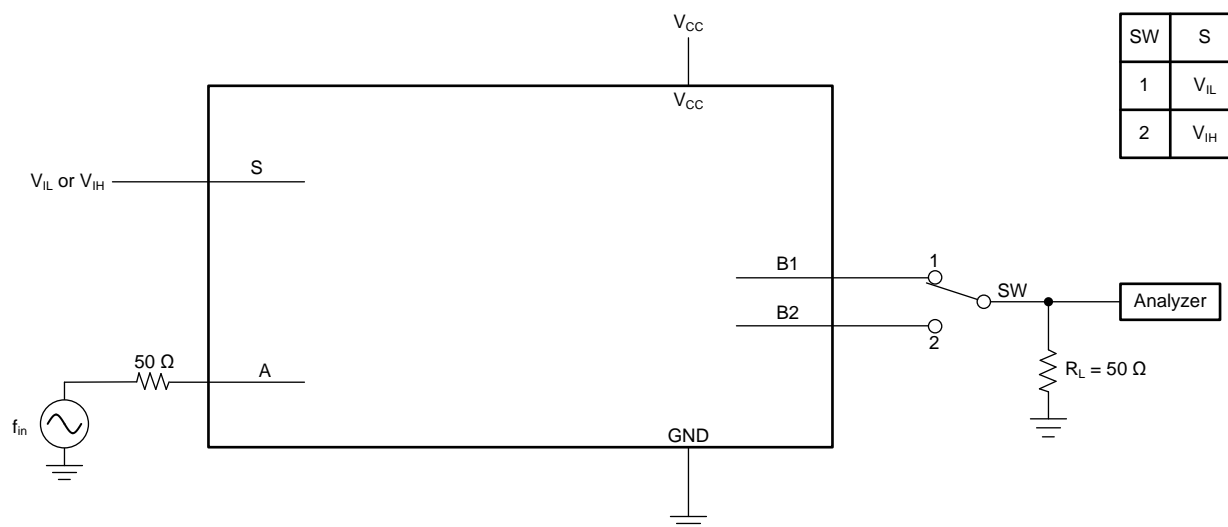


Figure 8. Feed Through

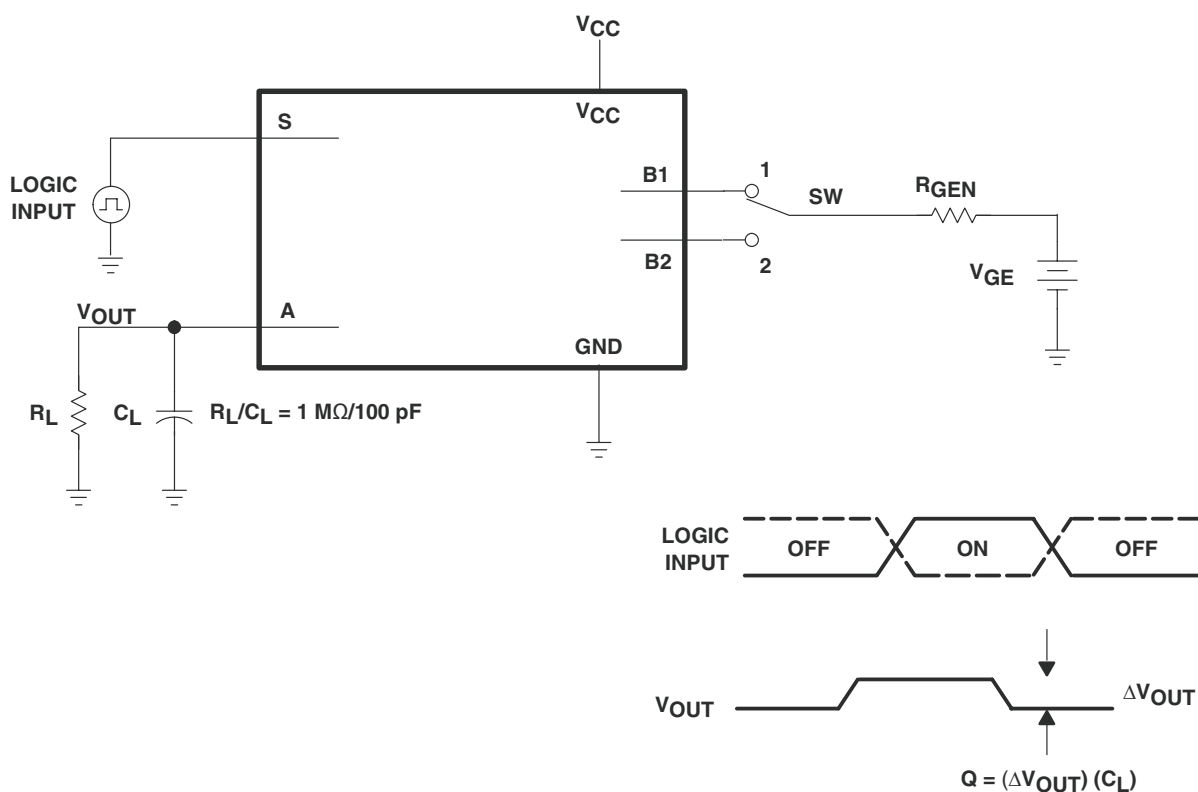


Figure 9. Charge-Injection Test

Parameter Measurement Information (continued)

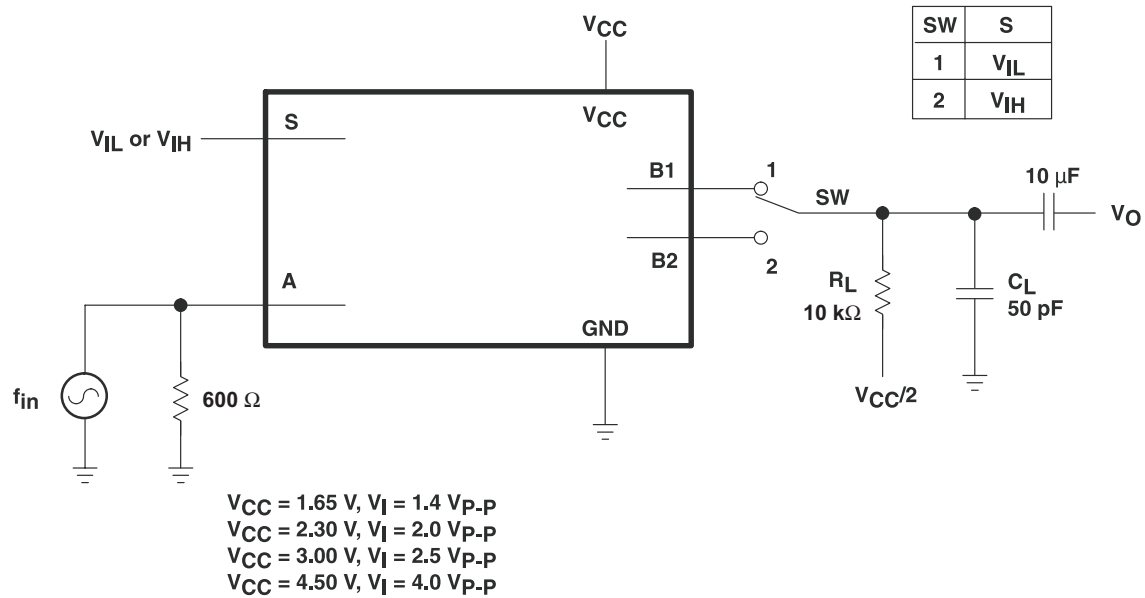


Figure 10. Total Harmonic Distortion

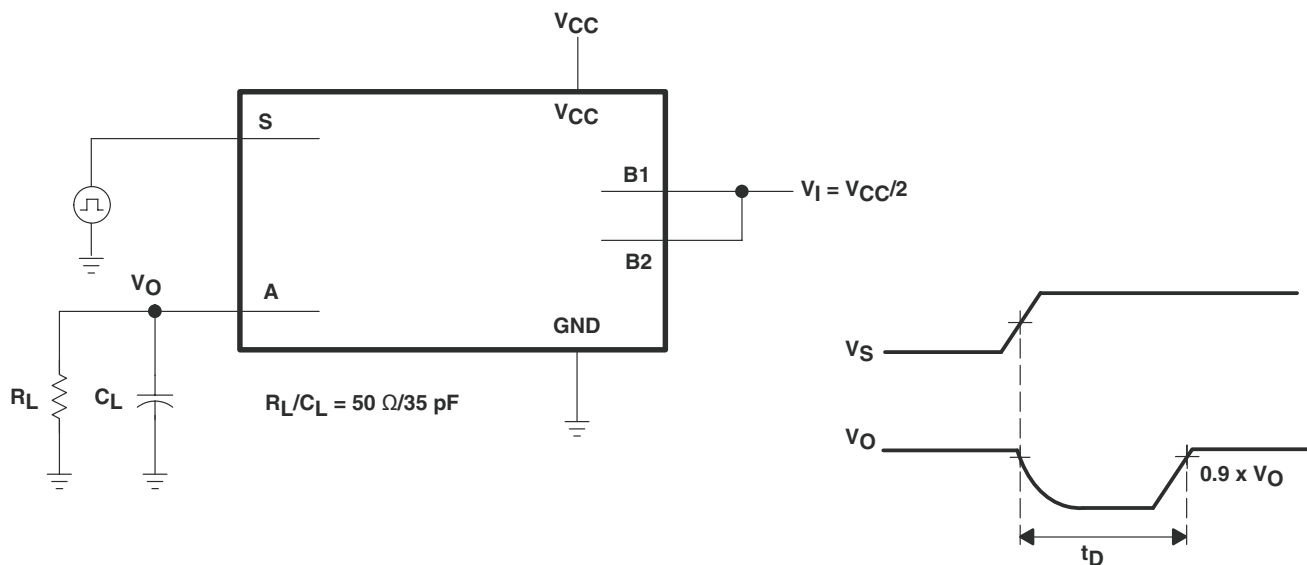


Figure 11. Break-Before-Make Internal Timing

8 Detailed Description

8.1 Overview

The SN74LVC1G3157 device is a single-pole double-throw (SPDT) analog switch designed for 1.65-V to 5.5-V V_{CC} operation. The SN74LVC1G3157 device can handle analog and digital signals. The device permits signals with amplitudes of up to V_{CC} (peak) to be transmitted in either direction.

8.2 Functional Block Diagram

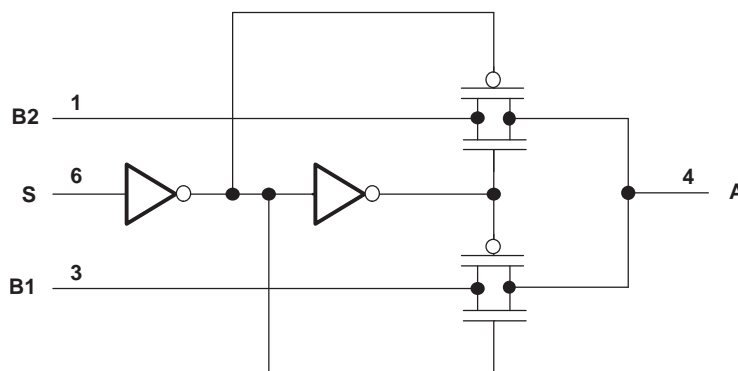


Figure 12. Logic Diagram (Positive Logic)

8.3 Feature Description

The 1.65-V to 5.5-V supply operation allows the device to function in many different systems comprised of different logic levels, allowing rail-to-rail signal switching. Either the B1 channel or the B2 channel is activated depending upon the control input. If the control input is low, B1 channel is selected. If the control input is high, B2 channel is selected.

8.4 Device Functional Modes

Table 1 lists the ON channel when one of the control inputs is selected.

Table 1. Function Table

CONTROL INPUTS	ON CHANNEL
L	B1
H	B2

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74LVC1G3157 SPDT analog switch is flexible enough for use in a variety of circuits such as analog audio routing, power-up monitor, memory sharing, and so on. For details on the applications, see [SCYB014](#).

9.2 Typical Application

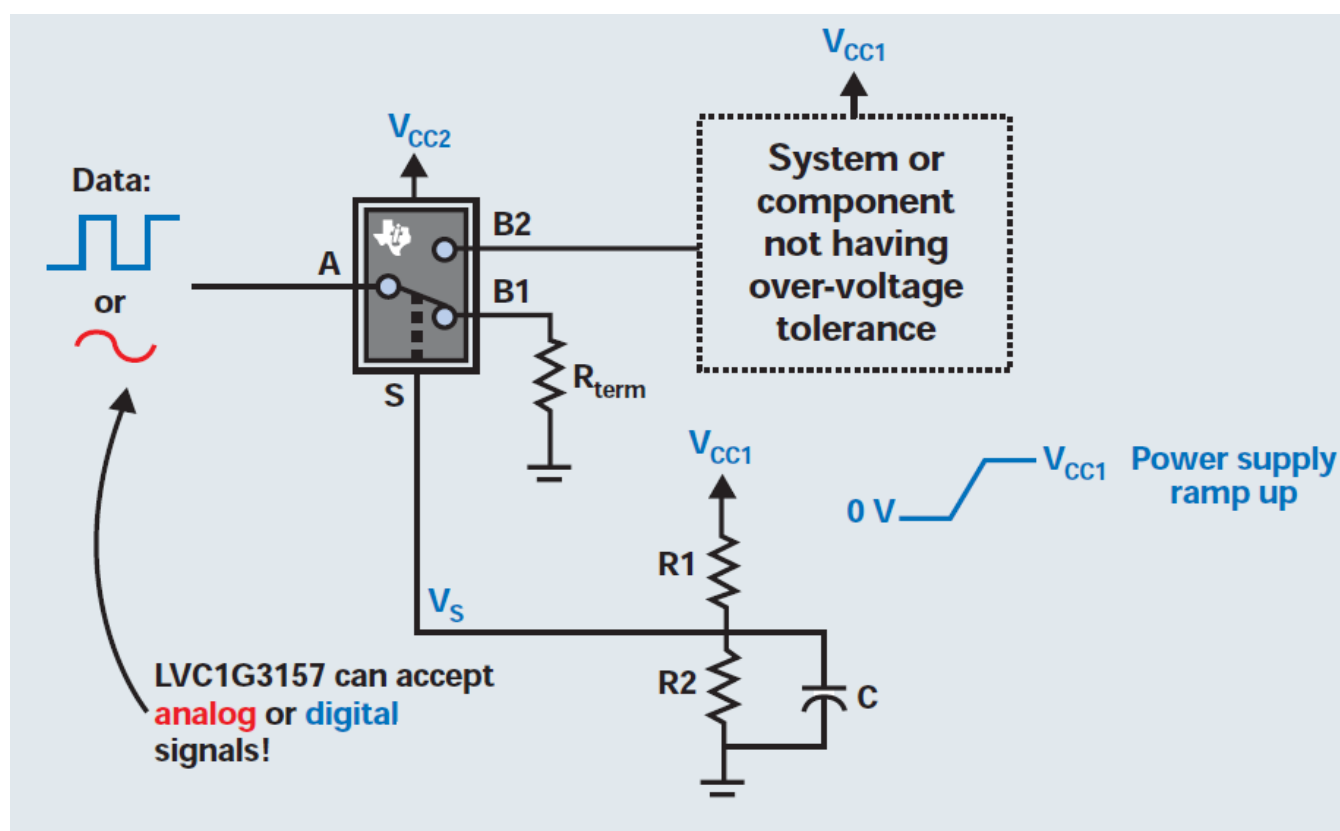


Figure 13. Typical Application Schematic

9.2.1 Design Requirements

The inputs can be analog or digital, but TI recommends waiting until V_{CC} has ramped to a level in [Recommended Operating Conditions](#) before applying any signals. Appropriate termination resistors should be used depending on the type of signal and specification. The Select pin should not be left floating; either pull up or pull down with a resistor that can be overdriven by a GPIO.

Typical Application (continued)

9.2.2 Detailed Design Procedure

Using this circuit idea, a system designer can ensure a component or subsystem power has ramped up before allowing signals to be applied to its input. This is useful for integrated circuits that do not have overvoltage tolerant inputs. The basic idea uses a resistor divider on the VCC1 power rail, which is ramping up. The RC time constant of the resistor divider further delays the voltage ramp on the select pin of the SPDT bus switch. By carefully selecting values for R1, R2, and C, it is possible to ensure that VCC1 will reach its nominal value before the path from A to B2 is established, thus preventing a signal being present on an I/O before the device/system is powered up. To ensure the minimum desired delay is achieved, the designer should use Equation 1 to calculate the time required from a transition from ground (0 V) to half the supply voltage (VCC1/2).

$$\text{Set } \left(\frac{R_2}{R_1 + R_2} \times V_{CC1} > V_{IH} \right) \text{ of the select pin} \quad (1)$$

Choose Rs and C to achieve the desired delay.

When Vs goes high, the signal will be passed.

9.2.3 Application Curve

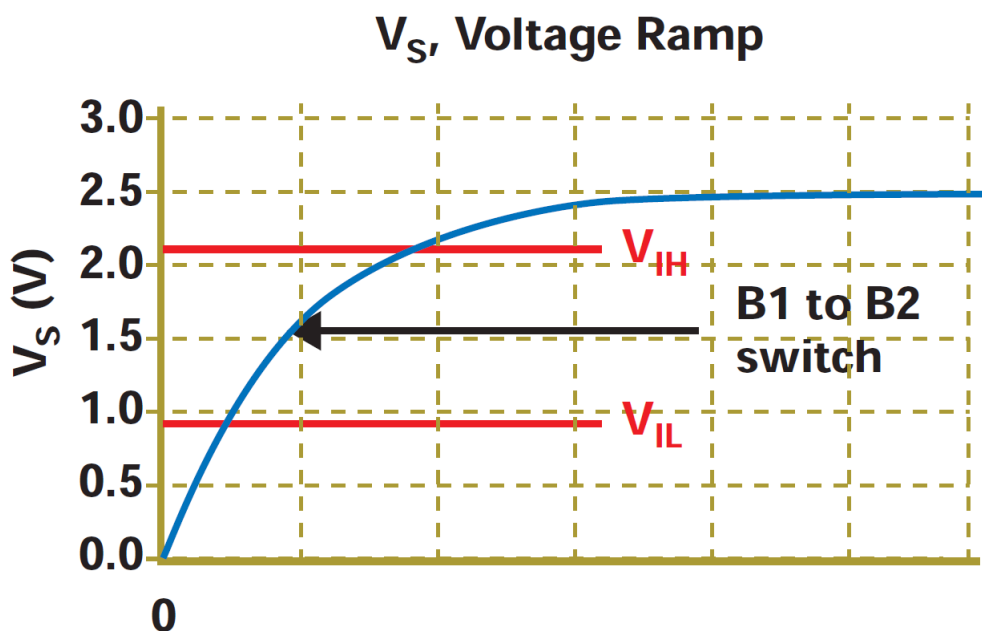


Figure 14. V_S Voltage Ramp

10 Power Supply Recommendations

Most systems have a common 3.3-V or 5-V rail that can supply the V_{CC} pin of this device. If this is not available, a Switch-Mode-Power-Supply (SMPS) or a Linear Dropout Regulator (LDO) can be used to provide supply to this device from another voltage rail.

11 Layout

11.1 Layout Guidelines

TI recommends keeping signal lines as short as possible. TI also recommends incorporating microstrip or stripline techniques when signal lines are greater than 1 inch in length. These traces must be designed with a characteristic impedance of either $50\ \Omega$ or $75\ \Omega$, as required by the application. Do not place this device too close to high-voltage switching components, as they may interfere with the device.

11.2 Layout Example

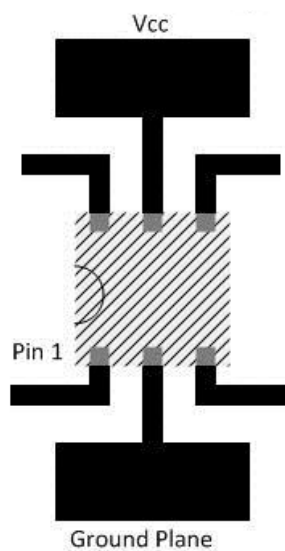


Figure 15. Recommended Layout Example

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- [Implications of Slow or Floating CMOS Inputs](#), SCBA004.
- [SN74LVC1G3157 and SN74LVC2G53 SPDT Analog Switches](#), SCYB014

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74LVC1G3157DBVRE4	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CC5F, CC5R)	Samples
74LVC1G3157DBVRG4	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CC5F, CC5R)	Samples
74LVC1G3157DCKRE4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C55, C5F, C5J, C5 K, C5R)	Samples
74LVC1G3157DCKRG4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C55, C5F, C5J, C5 K, C5R)	Samples
74LVC1G3157DRYRG4	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C5	Samples
SN74LVC1G3157DBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CC55, CC5F, CC5K, CC5R)	Samples
SN74LVC1G3157DCK3	ACTIVE	SC70	DCK	6	3000	RoHS & Non-Green	SNBI	Level-1-260C-UNLIM	-40 to 125	C5Z	Samples
SN74LVC1G3157DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C55, C5F, C5J, C5 K, C5R)	Samples
SN74LVC1G3157DRLR	ACTIVE	SOT-5X3	DRL	6	4000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(C57, C5R)	Samples
SN74LVC1G3157DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	C5	Samples
SN74LVC1G3157DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C5	Samples
SN74LVC1G3157DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	C5	Samples
SN74LVC1G3157DTBR	ACTIVE	X2SON	DTB	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7X	Samples
SN74LVC1G3157YZPR	ACTIVE	DSBGA	YZP	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	C5N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

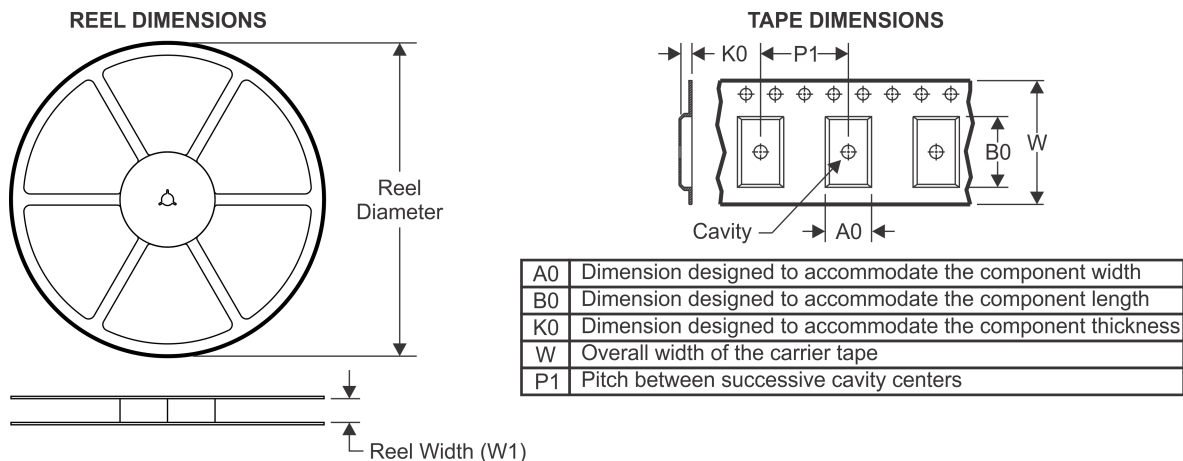
OTHER QUALIFIED VERSIONS OF SN74LVC1G3157 :

- Automotive: [SN74LVC1G3157-Q1](#)

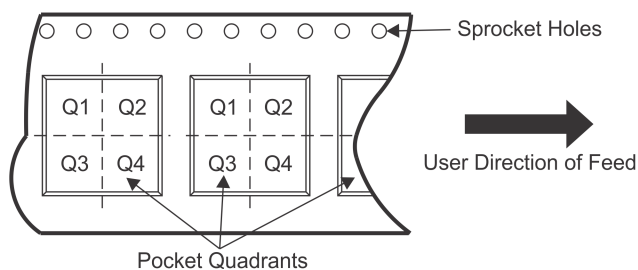
NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION



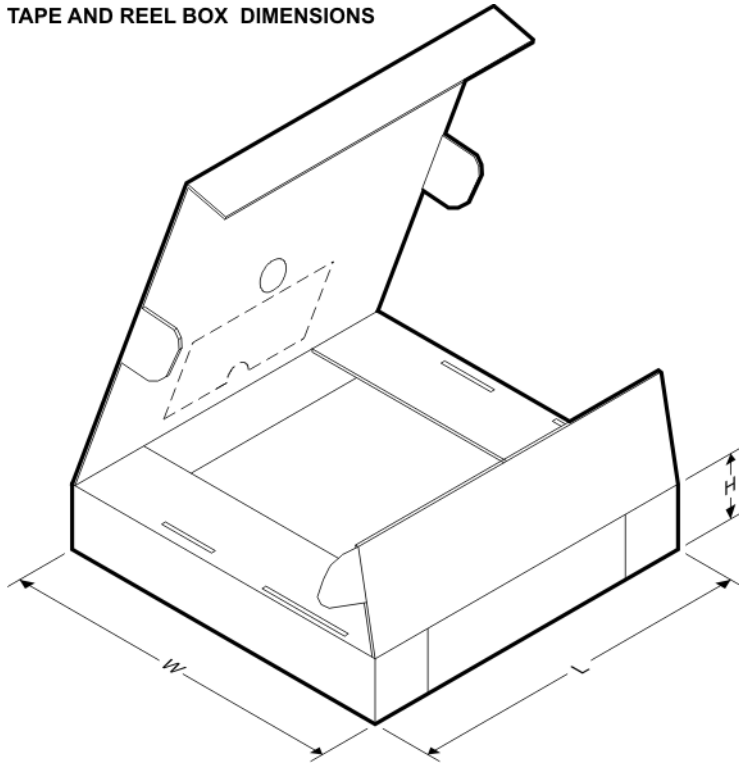
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74LVC1G3157DBVRG4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G3157DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G3157DCKR	SC70	DCK	6	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G3157DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G3157DRLR	SOT-5X3	DRL	6	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1G3157DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74LVC1G3157DRY2	SON	DRY	6	5000	180.0	8.4	1.65	1.2	0.7	4.0	8.0	Q3
SN74LVC1G3157DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G3157DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G3157DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q2
SN74LVC1G3157DTBR	X2SON	DTB	6	3000	180.0	9.5	0.94	1.13	0.41	2.0	8.0	Q2
SN74LVC1G3157YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74LVC1G3157DBVRG4	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G3157DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G3157DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1G3157DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1G3157DRLR	SOT-5X3	DRL	6	4000	202.0	201.0	28.0
SN74LVC1G3157DRLR	SOT-5X3	DRL	6	4000	184.0	184.0	19.0
SN74LVC1G3157DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G3157DRY2	SON	DRY	6	5000	202.0	201.0	28.0
SN74LVC1G3157DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G3157DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G3157DSFR	SON	DSF	6	5000	183.0	183.0	20.0
SN74LVC1G3157DTBR	X2SON	DTB	6	3000	189.0	185.0	36.0
SN74LVC1G3157YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

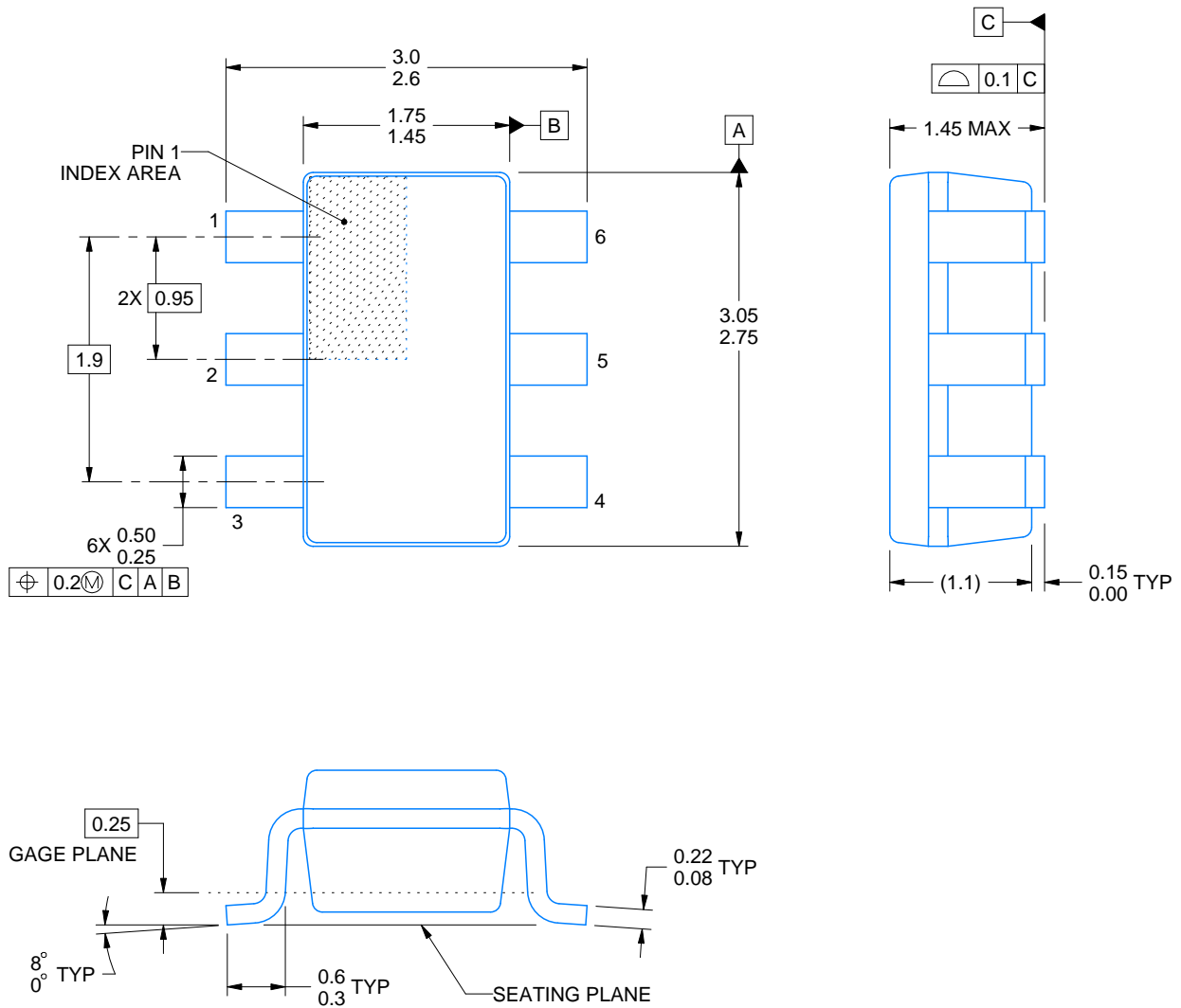
DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214840/C 06/2021

NOTES:

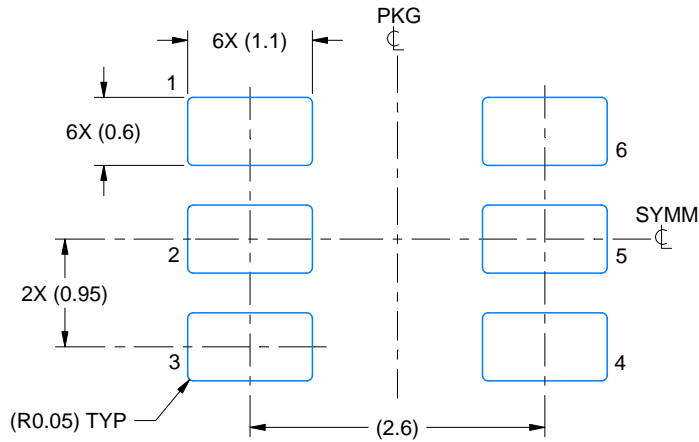
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

EXAMPLE BOARD LAYOUT

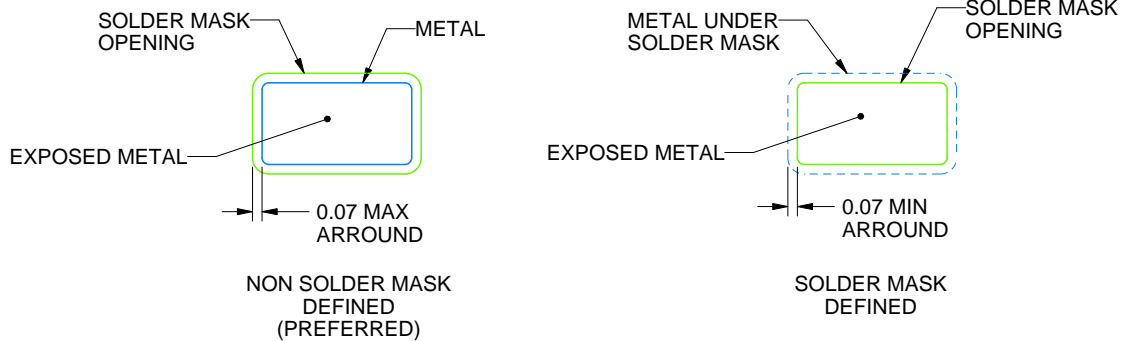
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/C 06/2021

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

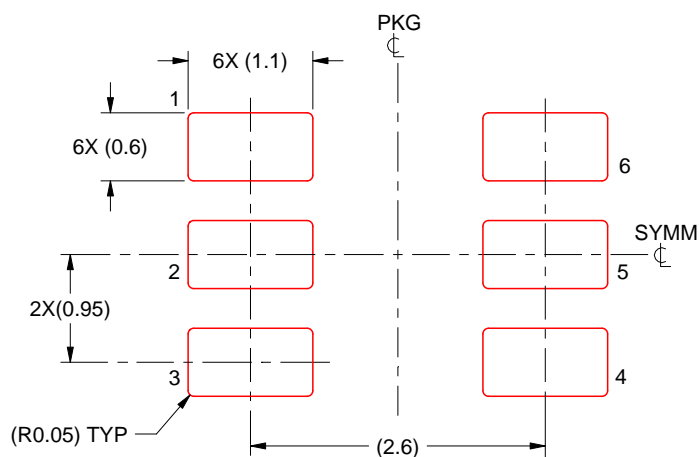
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/C 06/2021

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



4093553-4/G 01/2007

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.

DCK (R-PDSO-G6)

PLASTIC SMALL OUTLINE



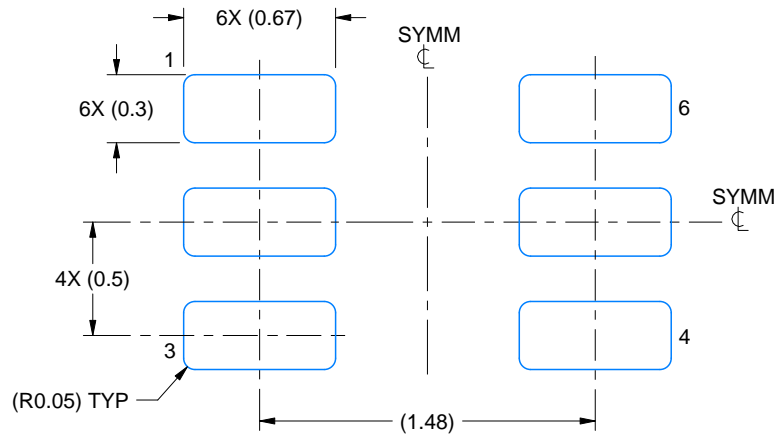
- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

EXAMPLE BOARD LAYOUT

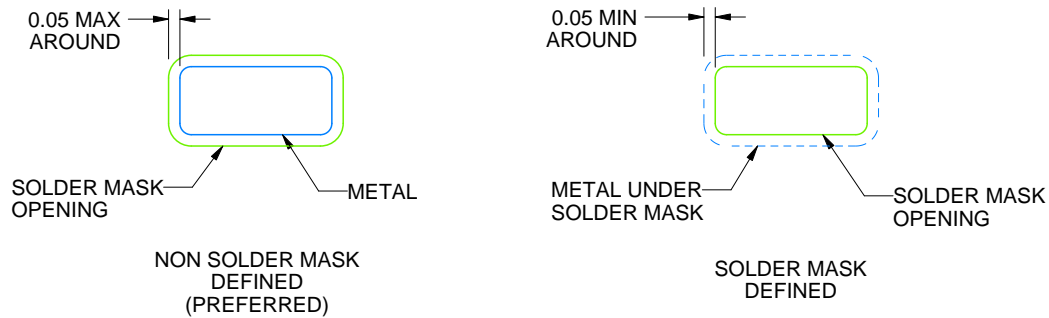
DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

4223266/C 12/2021

NOTES: (continued)

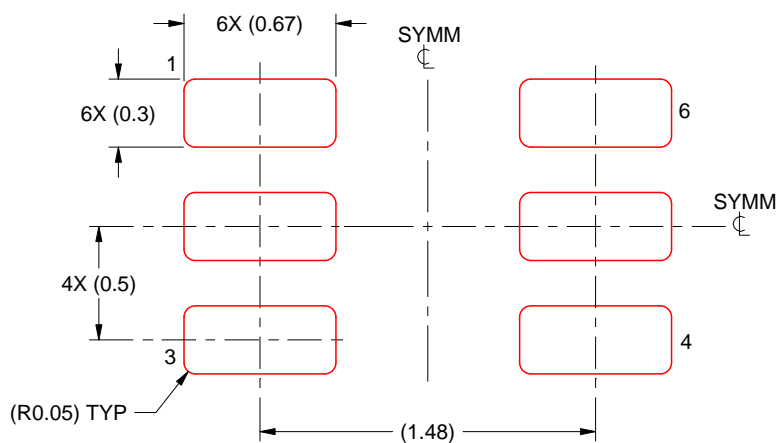
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4223266/C 12/2021

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

DRY 6

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4207181/G



USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4222894/A 01/2018

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
EXPOSED METAL SHOWN
SCALE:40X



SOLDER MASK DETAILS

4222894/A 01/2018

NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slue271).

EXAMPLE STENCIL DESIGN

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222894/A 01/2018

NOTES: (continued)

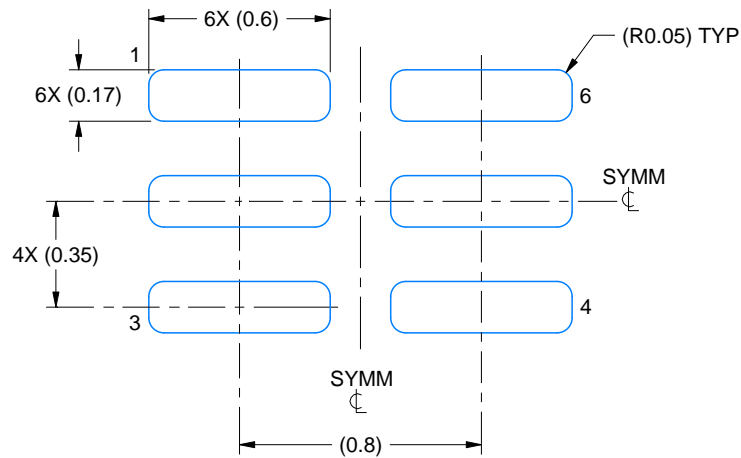
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

EXAMPLE BOARD LAYOUT

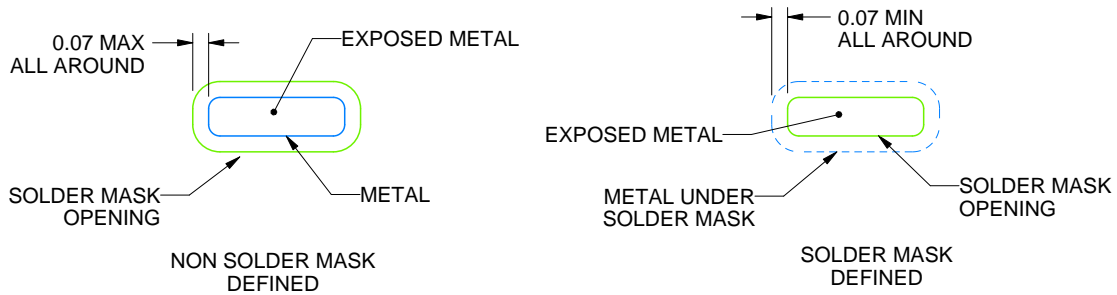
DSF0006A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:40X



SOLDER MASK DETAILS

4220597/A 06/2017

NOTES: (continued)

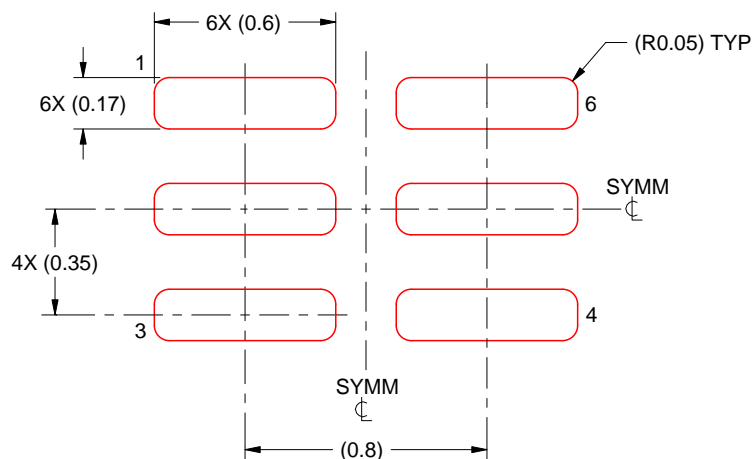
4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slue271).

EXAMPLE STENCIL DESIGN

DSF0006A

X2SON - 0.4 mm max height

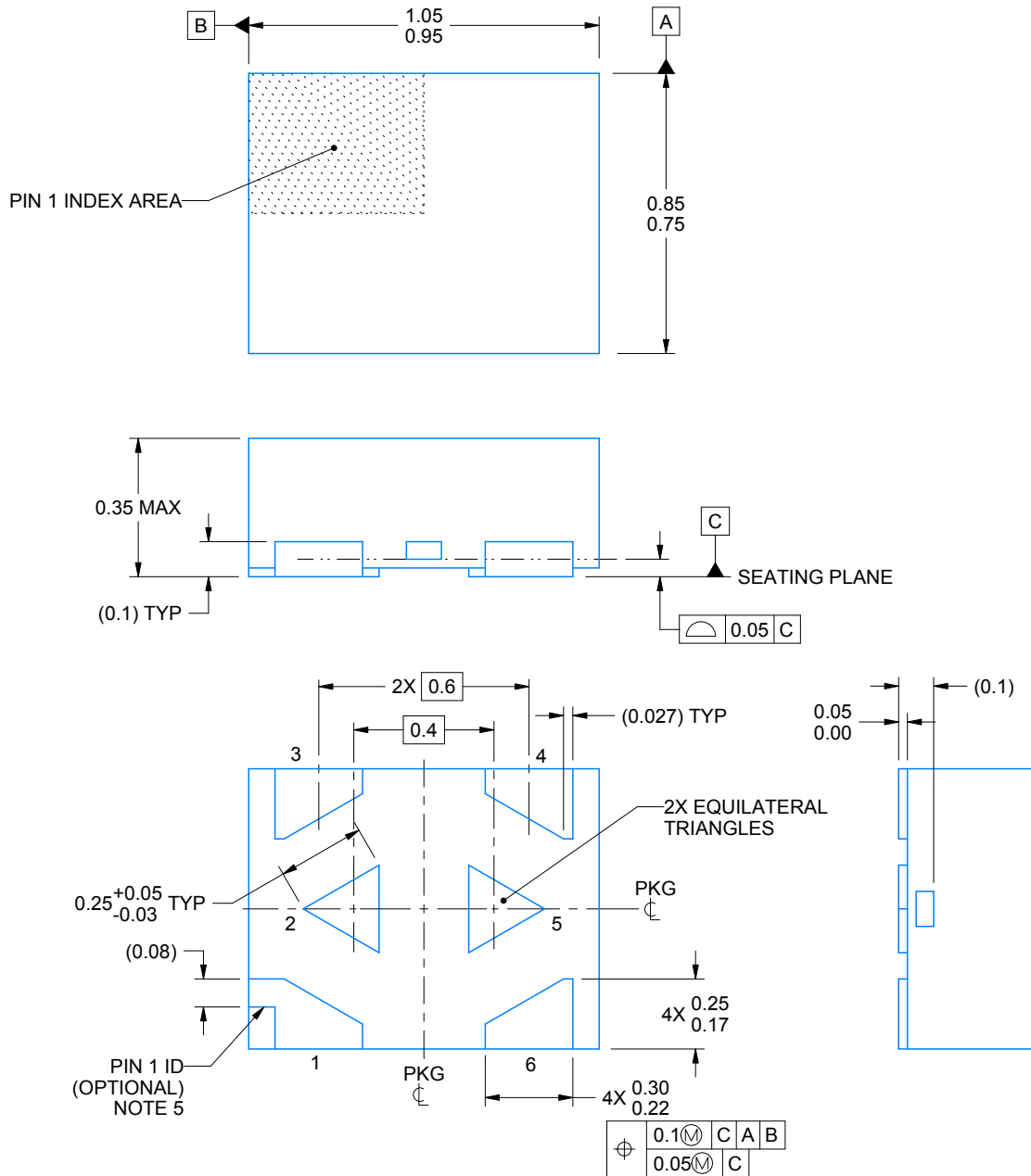
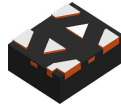
PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:40X

4220597/A 06/2017

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4223406/C 02/2019

NOTES:

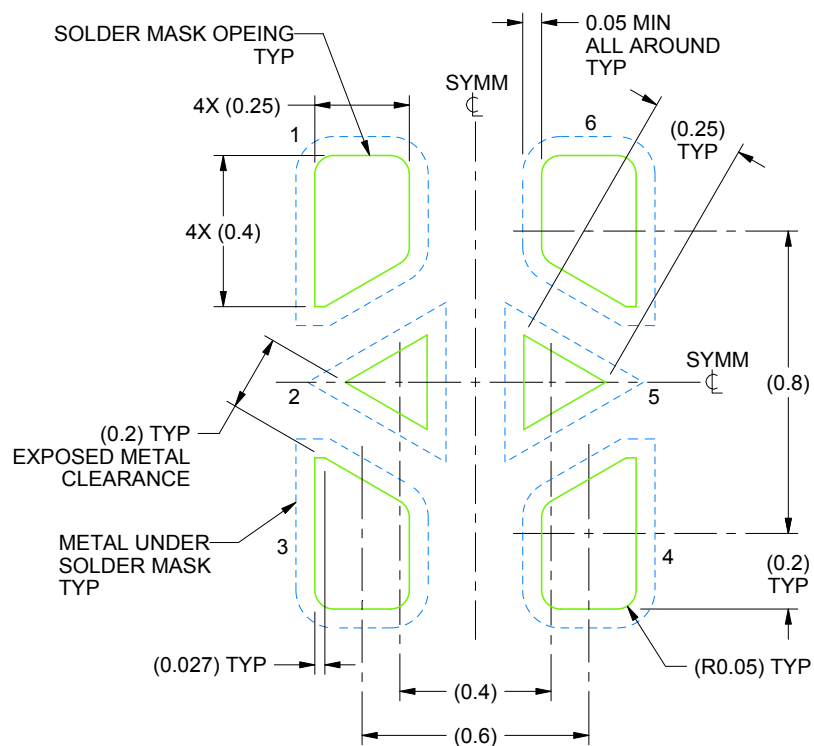
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. The size and shape of this feature may vary.
5. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.

EXAMPLE BOARD LAYOUT

DTB0006A

X2SON - 0.35 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SOLDER MASK DEFINED
SCALE:50X

4223406/C 02/2019

NOTES: (continued)

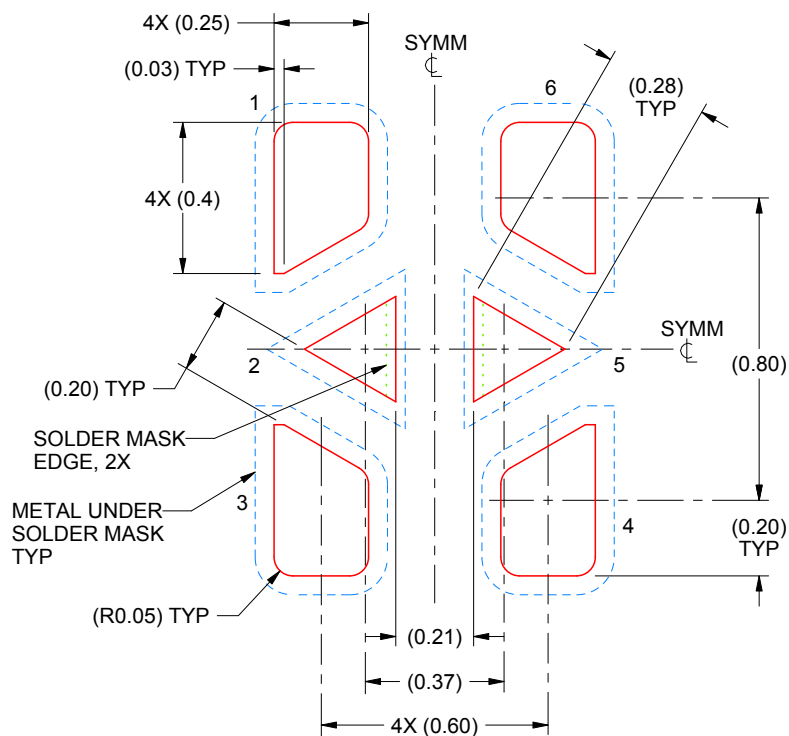
6. This package is designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slue271).
7. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DTB0006A

X2SON - 0.35 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.07 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:50X

4223406/C 02/2019

NOTES: (continued)

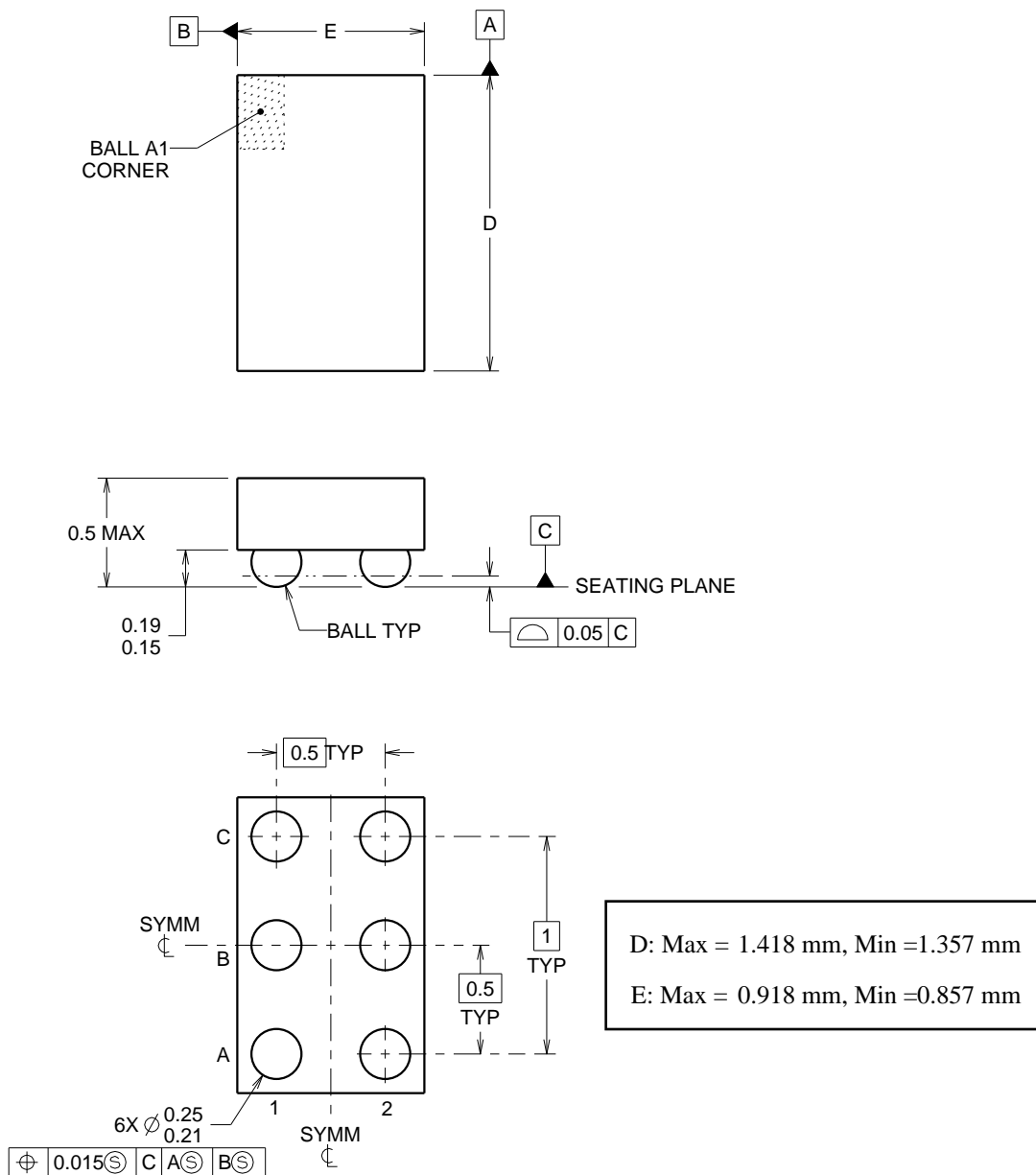
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



4219524/A 06/2014

NOTES:

NanoFree Is a trademark of Texas Instruments.

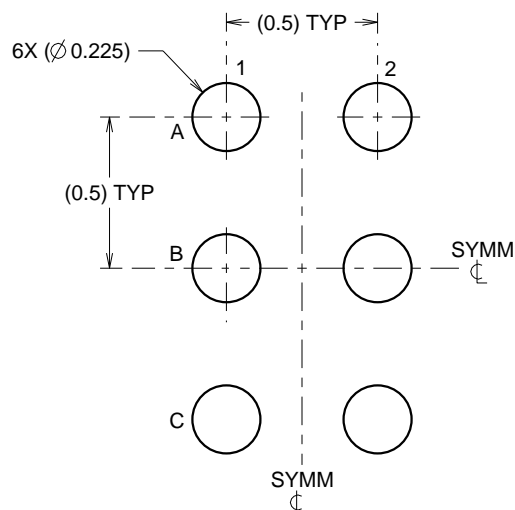
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

EXAMPLE BOARD LAYOUT

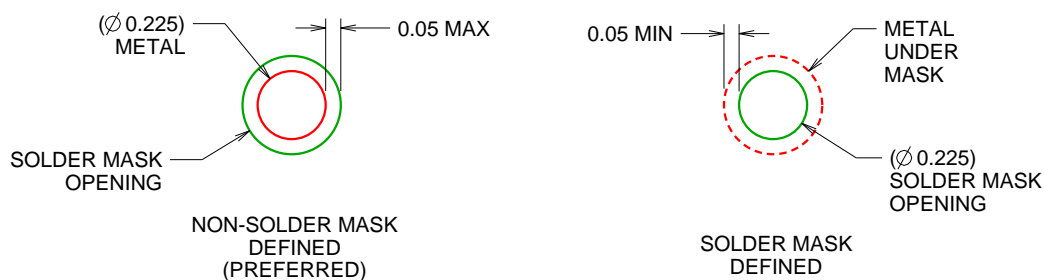
YZP0006

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS
NOT TO SCALE

4219524/A 06/2014

NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).

EXAMPLE STENCIL DESIGN

YZP0006

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4219524/A 06/2014

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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